

# **LM382 Low Noise Dual Preamplifier**

#### **General Description**

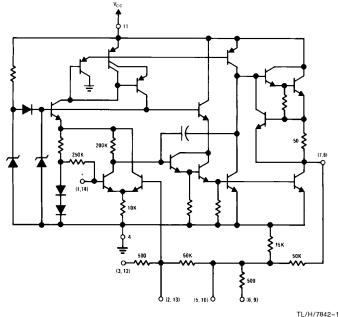
The LM382 is a dual preamplifier for the amplification of low level signals in applications requiring optimum noise performance. Each of the two amplifiers is completely independent, with individual internal power supply decoupler-regulator, providing 120 dB supply rejection and 60 dB channel separation. Other outstanding features include high gain (100 dB), and wide power bandwidth (75 kHz, 20 Vp-p). The LM382 operates from a single supply across the wide range of 9V to 40V.

A resistor matrix is provided on the chip to allow the user to select a variety of closed loop gain options and frequency response characteristics such as flat-band, NAB or RIAA equalization. The circuit is supplied in the 14 lead dual-inline package.

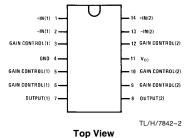
#### **Features**

- Low noise 0.8  $\mu$ V total equivalent input noise
- High gain 100 dB open loop
- Single supply operation
- Wide supply range 9V to 40V
- Power supply rejection 120 dB
- Large output voltage swing
- Wide bandwidth 15 MHz unity gain
   Power bandwidth 75 kHz, 20 Vp-p
- Internally compensated
- Short circuit protected

# **Schematic and Connection Diagrams**



#### **Dual-In-Line Package**



Order Number LM382N See NS Package Number N14A

Absolute Maximum Ratings
If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage

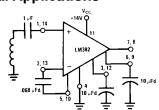
Power Dissipation (Note 1) 1.56 W Operating Temperature Range  $0^{\circ}C$  to  $+70^{\circ}C$ Storage Temperature Range  $-65^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$ Lead Temperature (Soldering, 10 sec.) +260°C

# **Electrical Characteristics** $T_A = 25^{\circ}C$ , $V_{CC} = 14V$ , unless otherwise stated.

Parameter	Conditions	Min	Тур	Max	Units	
Voltage Gain	Open Loop, f = 100 Hz		100,000		V/V	
Supply Current	$V_{CC}$ 9V to 40V, $R_L = \infty$		10	20	mA	
Output DC Voltage			6		V	
Input Resistance (Positive Input) (Negative Input)			100		kΩ	
,			200		kΩ	
Input Current (Negative Input)			0.5		μΑ	
Output Resistance	Open Loop		150		Ω	
Output Current	Source		8		mA	
	Sink		2		mA	
Output Voltage Swing	Peak-to-Peak, R <sub>L</sub> = 10k		12		V	
Unity Gain Bandwidth			15		MHz	
Power Bandwidth	20 Vp-p (V <sub>CC</sub> = 24V)		75		kHz	
Maximum Input Voltage	Linear Operation			300	mVrms	
Supply Rejection Ratio	f = 1 kHz		120		dB	
Channel Separation	f = 1 kHz	40	60		dB	
Total Harmonic Distortion	60 dB Gain, f = 1 kHz		0.1	0.3	%	
Total Equivalent Input Noise	$R_S = 600\Omega$ , 100–10,000 Hz (Flat Response Circuit)		0.8	1.2	μVrms	

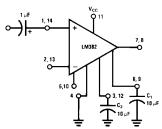
Note 1: For operation in ambient temperatures above 25°C, the device must be derated based on a 150°C maximum junction temperature and a thermal resistance

# **Typical Applications**

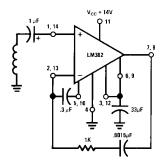


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Tape Preamp (NAB Equalization)



Flat Response — Fixed Gain Configuration

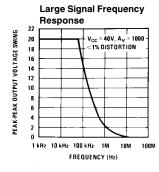


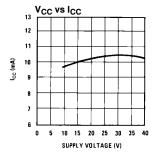
TL/H/7842-4

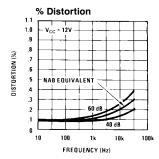
## Phono Preamp (RIAA Equalization)

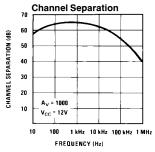
Capacitor	Gain		
C1 Only	40 dB		
C2 Only	55 dB		
C1 & C2	80 dB		

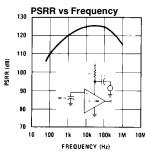
# **Typical Performance Characteristics**

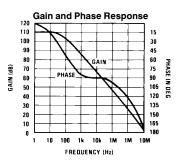


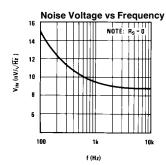


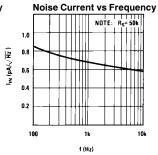


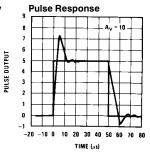






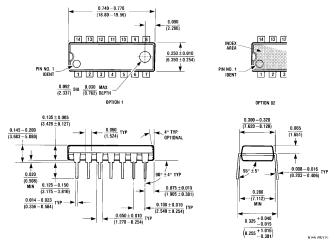






TL/H/7842-6

## Physical Dimensions inches (millimeters)



Molded Dual-In-Line Package (N) Order Number LM382N NS Package Number N14A

## LIFE SUPPORT POLICY

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- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



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